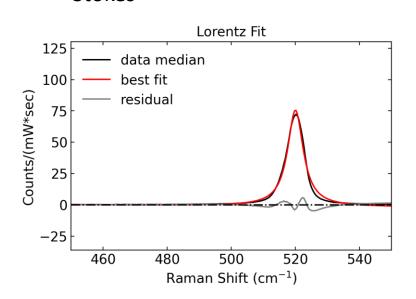
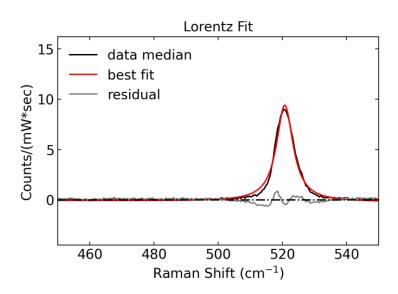
Room Temperature (0 mA)

Stokes

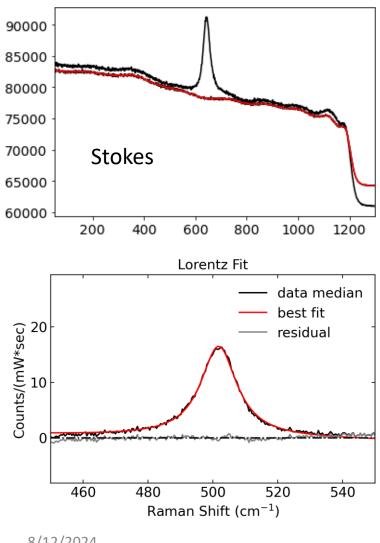


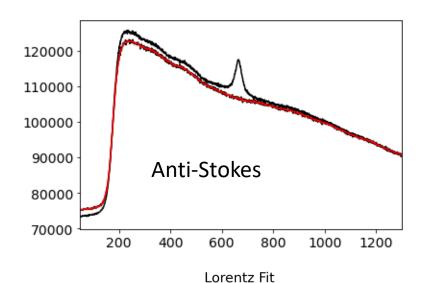
Anti-Stokes

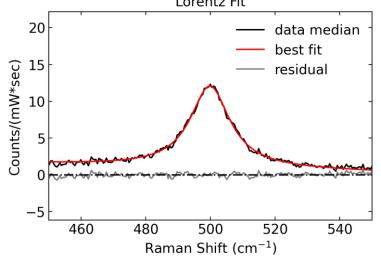


$$-\operatorname{Im}(D^{0}(\omega)) = -\operatorname{Im}\left(\frac{\omega_{0}}{\omega^{2}\omega_{0}^{2} + i\Gamma\omega_{0}}\right) => A \cdot \frac{\Gamma\omega}{(\omega^{2} - \omega_{0}^{2})^{2} + \Gamma^{2}\omega^{2}}$$

Si on $TiO_2 - 08/09/2024$

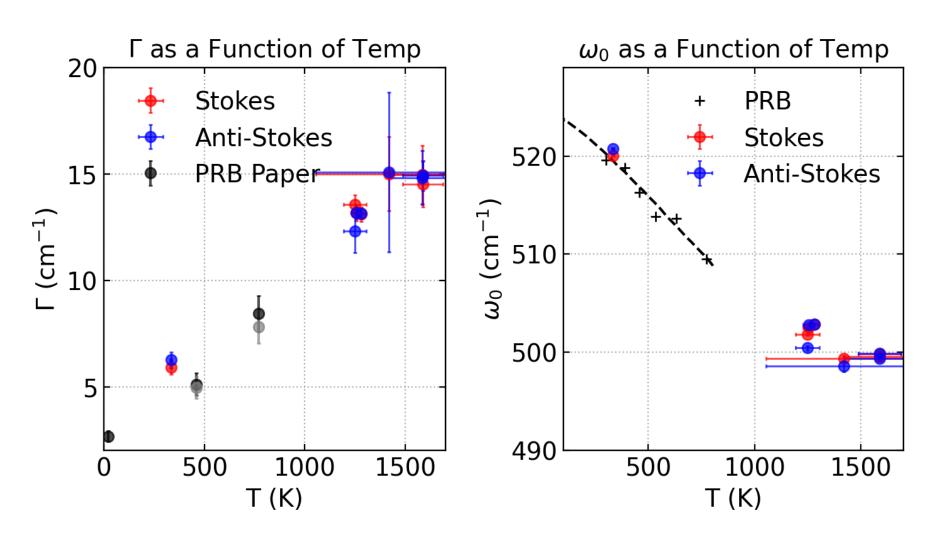




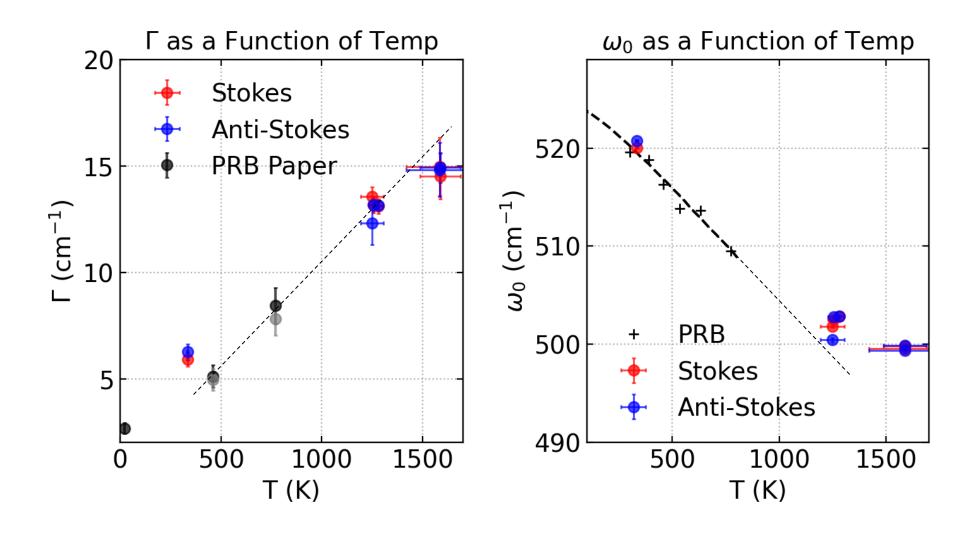


Strong backgrounds

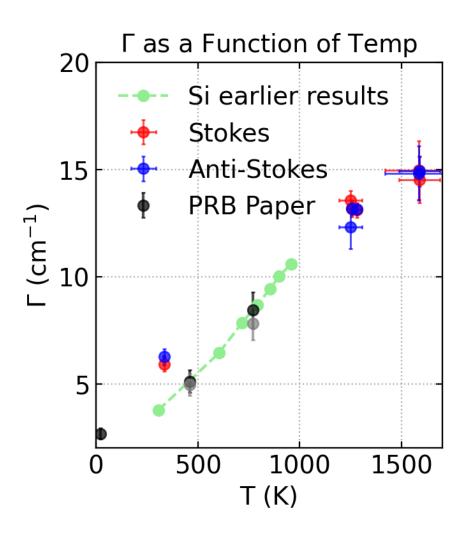
Background subtraction results in reasonable fitting of the Si phonon

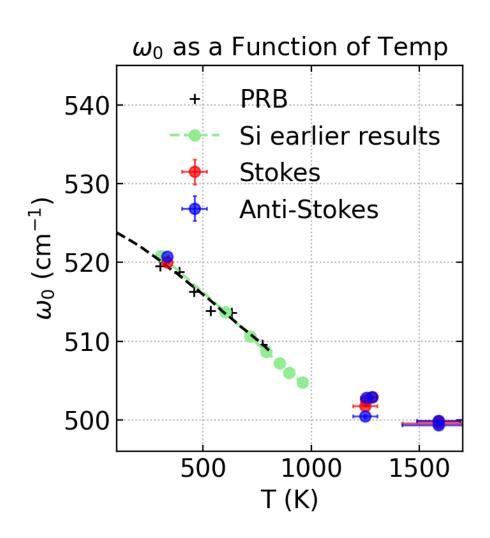


Data at 80 mA has large errors, due to large background. Maybe ist better to leave this data point out (next slide).

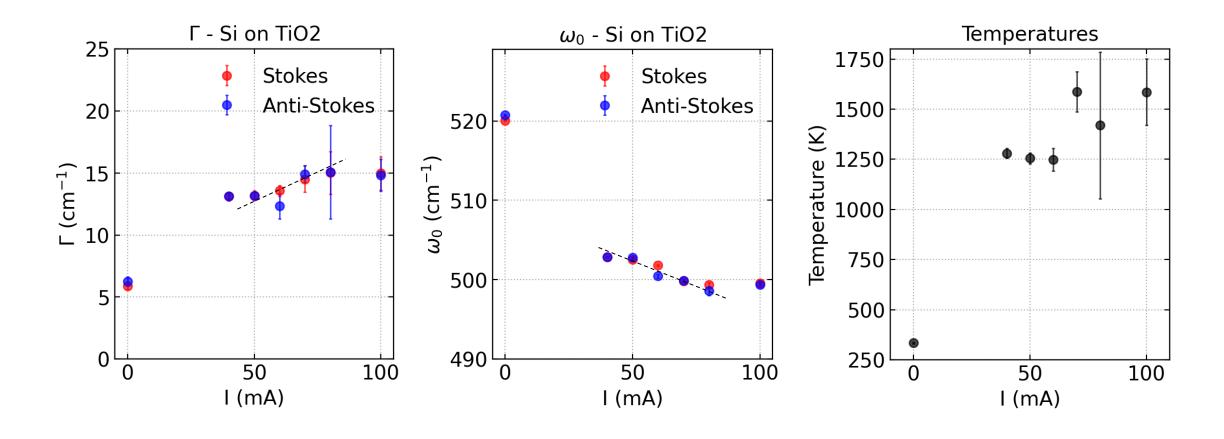


Si on $TiO_2 - 08/09/2024$





Si on $TiO_2 - 08/09/2024$



Temperature results:

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0 mA 333.97 ± 1.49 K

40 mA 1280.37 ± 7.89 K

50 mA 1255.22 ± 8.76 K

60 mA 1248.58 ± 18.87 K

70 mA 1588.00 ± 33.24 K

80 mA 1419.47 ± 121.72 K

100 mA 1586.08 ± 55.47 K
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